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[54] **VISIBLE LIGHT EMITTING DIODES FABRICATED FROM SOLUBLE SEMICONDUCTING POLYMERS**

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257/103

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[57] **ABSTRACT**

Visible light LEDs are produced having a layer of conjugated polymer which is cast directly from solution or formed as a gel-processed admixture with a carrier polymer. The LEDs can be formed so as to emit polarized light.

26 Claims, 1 Drawing Sheet

